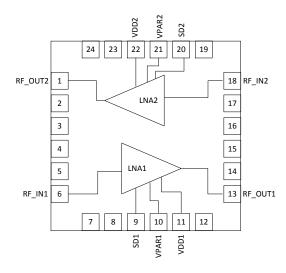


# **RFLA9003**

Dual Low Noise Amplifier Module 1710MHz to 2180MHz

RFMD's RFLA9003 is a dual Low Noise Amplifier module with external connections to both LNAs. These LNAs feature a shutdown mode to turn off the LNA and provide up to 15dBm drive level without gain expansion and self-biasing in shutdown mode. Noise figure of 1.2dB and input P1dB of -3.5dBm make this component ideal for receiver input lineups. The RFLA9003 is packaged in a small 4.0mm x 4.0mm leadless laminate MCM. This module is internally matched to  $50\Omega$  on all RF ports making it easy to use with no external matching components required.



Functional Block Diagram

## **Ordering Information**

RFLA9003SQ	Sample bag with 25 pieces
RFLA9003SR	7" Reel with 100 pieces
RFLA9003TR13	13" Reel with 2500 pieces
RFLA9003PCK-410	1710MHz to 2180MHz PCBA with 5-piece sample bag



Package: MCM, 24-pin, 4.0mm x 4.0mm

#### **Features**

- Frequency Range 1710MHz to 2180MHz
- Internally Matched to 50Ω on all RF Ports
- Shutdown Mode with +40dB Isolation
- Gain = >15dB per LNA
- Noise Figure of 1.2dB Typical
- Single +4.0V Supply
- Small 24-Pin, 4.0mm x 4.0mm, Multi-Chip Module (MCM)

#### **Applications**

- Cellular Repeaters
- General Purpose LNA



# **Absolute Maximum Ratings**

Parameter	Rating	Unit
Supply Voltage	+5.5	$V_{DC}$
Control Voltage	+5.5	$V_{DC}$
DC Supply Current	130	mA
Power Dissipation	770	mW
Max RF Input Power	15	dBm
Operating Temperature (T <sub>CASE</sub> )	-40 to +85	°C
Storage Temperature Range	-40 to +150	°C
Junction Temperature (T <sub>J</sub> )	150	°C
ESD Rating - Human Body Model (HBM)	1000 (Class 1C)	V
Moisture Sensitivity Level	MSL3	



Caution! ESD sensitive device.



RFMD Green: RoHS status based on EU Directive 2011/65/EU (at time of this document revision), halogen free per IEC 61249-2-21, < 1000ppm each of antimony trioxide in polymeric materials and red phosphorus as a flame retardant, and <2% antimony in solder.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

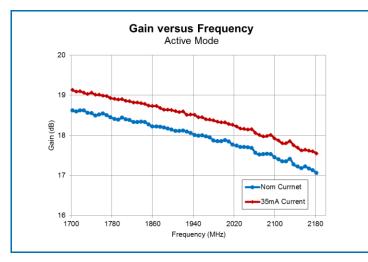
#### **Nominal Operating Parameters**

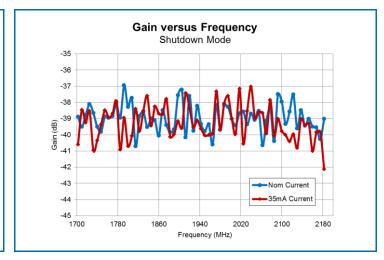
B. Carlotte	Specification					
Parameter	Min	Тур	Max	Unit	Condition	
Individual LNA Performance					Temp = 25°C, V <sub>CC</sub> = 4V, Standard Application Circuit	
Frequency Range	1710		2180	MHz		
Gain (On Mode)	15	18	21	dB	SD = 0V	
Noise Figure		1.2	1.6	dB		
Input P1dB	-6.5	-3.5		dBm		
Input IP3	6.6	9		dBm		
Gain (Off Mode)		-39		dB	SD = 4V	
Gain Delta	>40			dB	Gain LNA (on mode) – Gain LNA (off mode), 1950MHz	
Input Return Loss		9.7		dB		
Output Return Loss		12.5		dB		
Isolation (LNA1 OUT to LNA2 IN)	35	47.5		dB		
Gain Compression Slope	-1.1	-1	-0.1	dB	Gain compresses monotonically with increased input power once saturated	
Overall Power Supply					Temp = 25°C, V <sub>CC</sub> = 4V, Standard Application Circuit	
Supply Voltage	3.5	4	5	V		
SD Voltage	0		VCC	V		
Logic High	1.7		VCC	V		
Logic Low	0		0.6	V		
Thermal Resistance		118		°C/W	85°C at 4.5V at 35mA	
Current	14	29	36	mA	On Mode, SD = 0V	
	0.5	3.5	6	mA	Off Mode, SD = 4V	

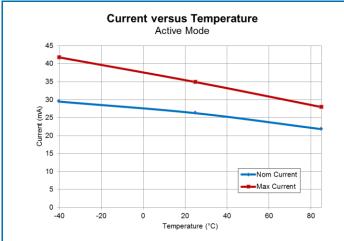
2 of 11

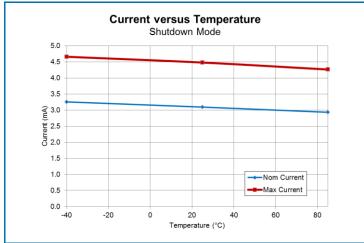


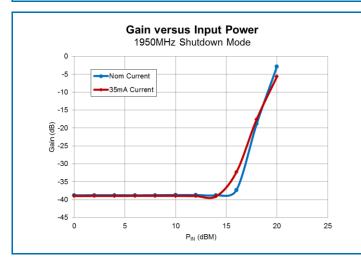
## Typical Performance: T=25°C, VDD = 4V unless otherwise noted

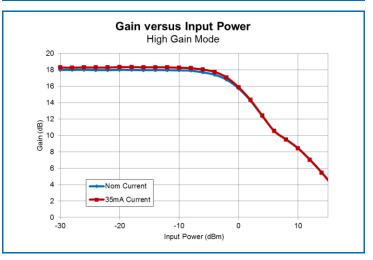






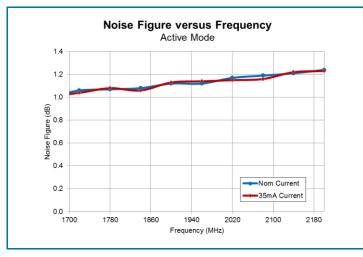


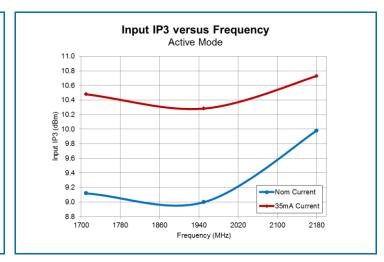


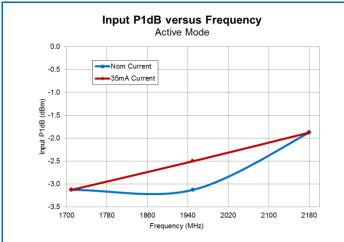


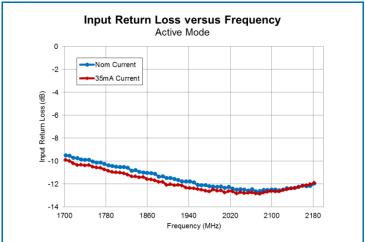


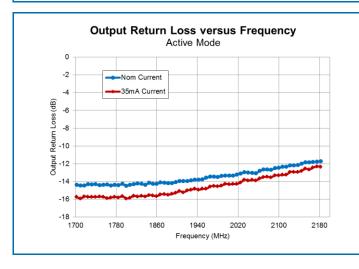
## Typical Performance: T=25°C, VDD = 4V unless otherwise noted

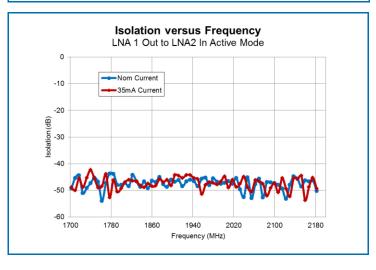






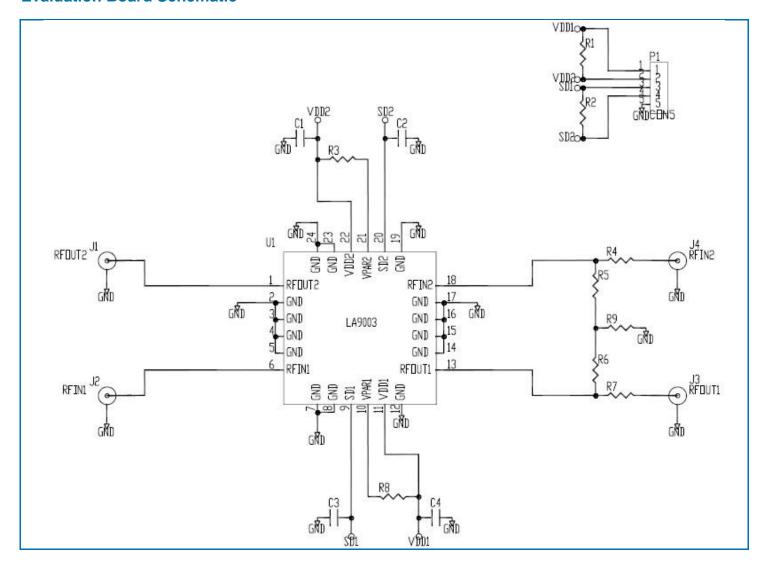








#### **Evaluation Board Schematic**





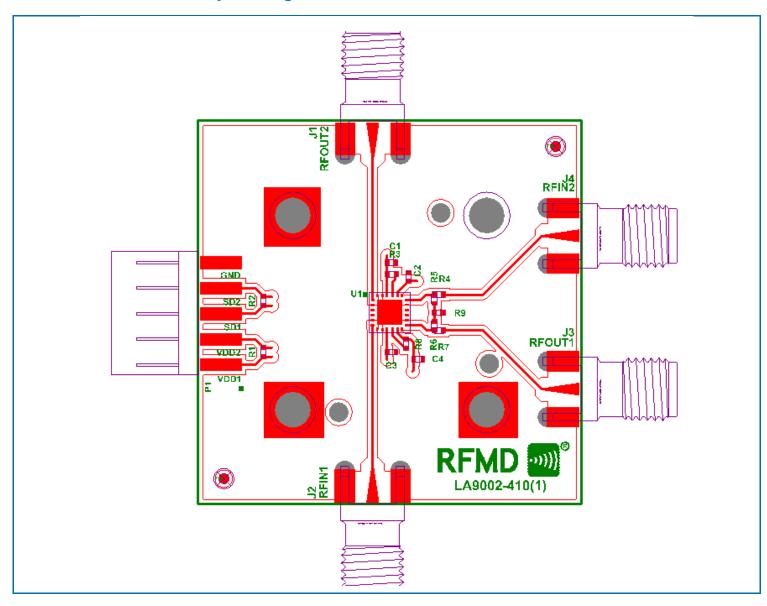
## **Evaluation Board Bill of Materials (BOM)**

Description	Reference Designator	Manufacturer	Manufacturer's P/N
Evaluation Board		DDI	LA9002-410(1)
RFLA9003 Module	U1	RFMD	RFLA9003
CAP, 0.1µF, 10% 16V, X7R, 0402	C1-C4	Murata Electronics	GRM155R71C104KA88D
CONN, SMA, END LNCH, UNIV, HYB MNT, FLT	J1-J4	Heilind Electronics	PER MAT-21-9003
RES, 0Ω, 0402	R5-R6	Kamaya, Inc.	RMC1/16SJPTH
CONN, HDR, ST, PLRZD, 9-PIN	P1	ITW Pancon	MPSS100-5C
DNP	R1-R4*, R7-R9*		

Note: Parts with \* following the Reference Designators should not be populated on PCBA.



# **Evaluation Board Assembly Drawing**





## **Pin Names and Descriptions**

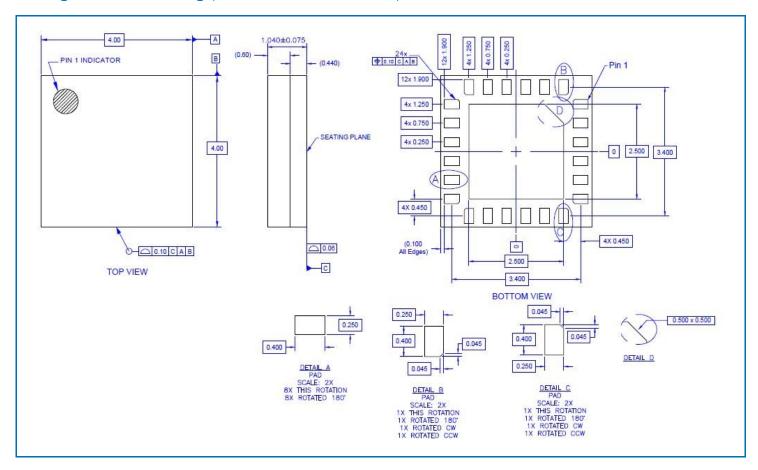
Pin	Name	Description
1	RF_OUT2	RF Output ; Internally $50\Omega$ matched and DC blocked
2	GND	Connect to low inductance path to ground
3	GND	Connect to low inductance path to ground
4	GND	Connect to low inductance path to ground
5	GND	Connect to low inductance path to ground
6	RF_IN1	RF Input; Internally 50Ω matched and DC blocked
7	GND	Connect to low inductance path to ground
8	GND	Connect to low inductance path to ground
9	SD1	Shut down pin for LNA1
10	VPAR1	Connection for external resistor to raise current when connected from this pad to V <sub>DD</sub> and to lower current when connected from this pad to ground
11	VDD1	VDD Supply, 10nF decoupling internal, supply for LNA1
12	GND	Connect to low inductance path to ground
13	RF_OUT1	RF Output; Internally 50Ω matched and DC blocked
14	GND	Connect to low inductance path to ground
15	GND	Connect to low inductance path to ground
16	GND	Connect to low inductance path to ground
17	GND	Connect to low inductance path to ground
18	RF_IN1	RF Input; Internally 50Ω matched and DC blocked
19	GND	Connect to low inductance path to ground
20	SD2	Shut down pin for LNA2
21	VPAR2	Connection for external resistor to raise current when connected from this pad to V <sub>DD</sub> and to lower current when connected from this pad to ground
22	VDD2	VDD Supply, 10nF decoupling internal, supply for LNA2
23	GND	Connect to low inductance path to ground
24	GND	Connect to low inductance path to ground

#### **Truth Table**

	SD1	SD2
LNA1 On	0	Х
LNA1 Off	1	Х
LNA2 On	Х	0
LNA2 Off	Х	1

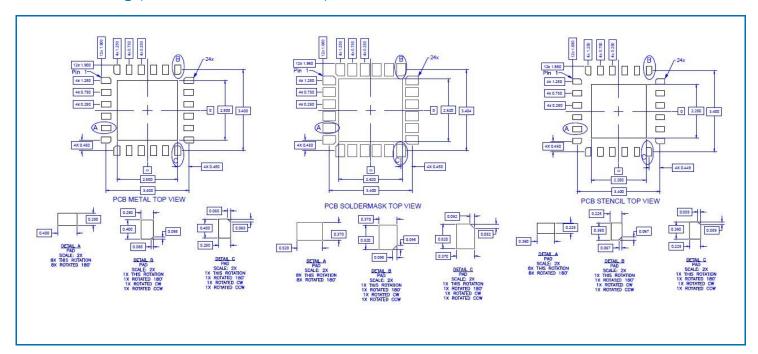


### Package Outline Drawing (Dimensions in millimeters)

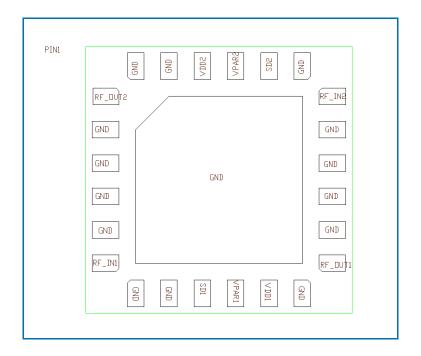




# Stencil Drawing (Dimensions in millimeters)

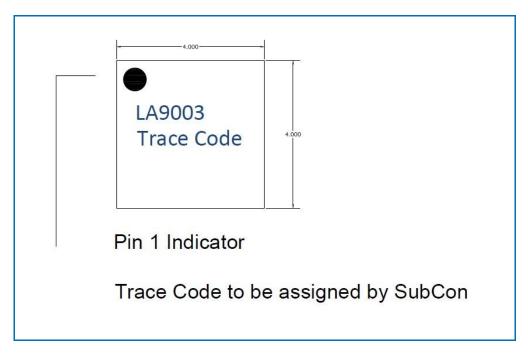


#### **IO Pattern Label**





## **Branding Diagram**





Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

#### Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов:
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001:
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

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